

5 Orderable Information

DEVICE	PACKAGE	OP TEMP	ECO PLAN	MSL	PACKING OPTION	SORT
CJ74HC4051AEN	SOP16	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 4000 Units / Reel	Active
CJ74HCT4051AEN	SOP16	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 4000 Units / Reel	Active
CJ74HC4051BEN	TSSOP16	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active
CJ74HCT4051BEN	TSSOP16	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active
CJ74HC4051QEN	QFN3.5x2.5-16L	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 3000 Units / Reel	Active
CJ74HCT4051QEN	QFN3.5x2.5-16L	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 3000 Units / Reel	Active

Note:

ECO PLAN: For the RoHS and Green certification standards of this product, please refer to the official report provided by JSCJ.

MSL: Moisture Sensitivity Level. Determined according to JEDEC industry standard classification.

SORT: Specifically defined as follows:

Active: Recommended for new products;

Customized: Products manufactured to meet the specific needs of customers;

Preview: The device has been released and has not been fully mass produced. The sample may or may not be available;

NoRD: It is not recommended to use the device for new design. The device is only produced for the needs of existing customers;

Obsolete: The device has been discontinued.

6 Pin Configuration and Marking Information

6.1 Pin Configuration

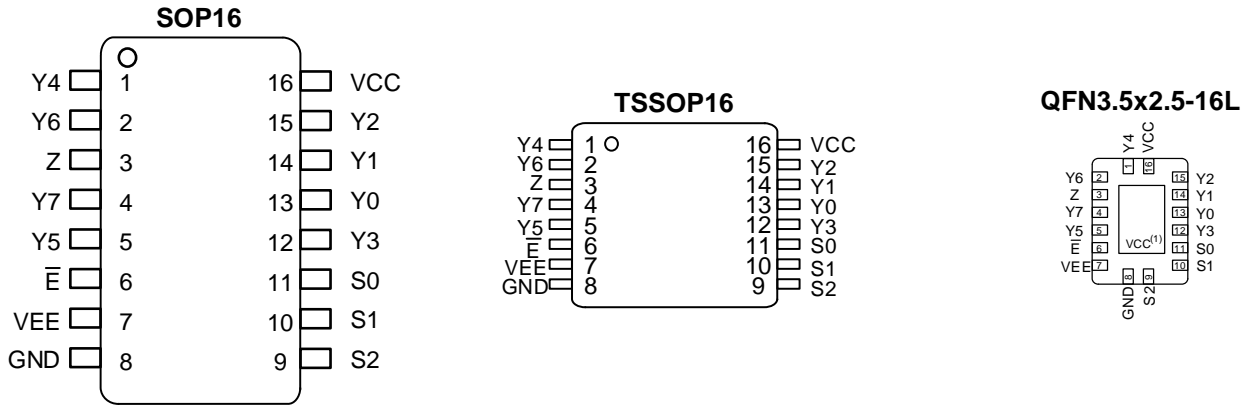


Figure 6-1 Pin configuration

Note:

- (1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to V_{cc}.

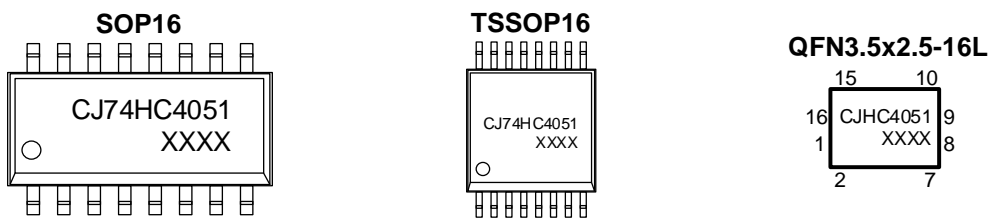
6.2 Pin Function

PIN		I/O ⁽¹⁾	DESCRIPTION
No.	NAME		
1	Y4	I/O	Independent input or output
2	Y6	I/O	Independent input or output
3	Z	I/O	Common output or input
4	Y7	I/O	Independent input or output
5	Y5	I/O	Independent input or output
6	\bar{E}	I	Enable input (active LOW)
7	VEE	P	Supply voltage
8	GND	G	Ground supply voltage
9	S2	I	Select input
10	S1	I	Select input
11	S0	I	Select input
12	Y3	I/O	Independent input or output
13	Y0	I/O	Independent input or output
14	Y1	I/O	Independent input or output
15	Y2	I/O	Independent input or output
16	VCC	P	Supply voltage

(1) I-Input, O-Output, P-Power, G-Ground

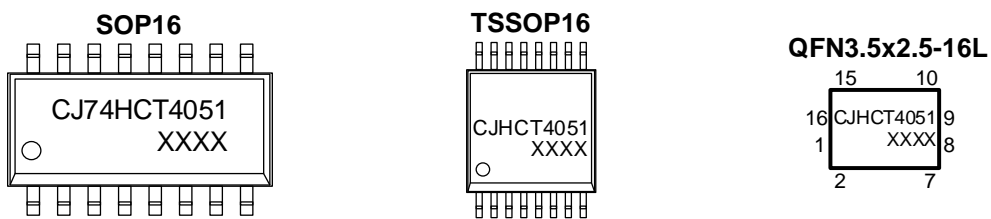
6.3 Marking Information

6.3.1 CJ74HC4051



XXXX: Code, indicates weekly record information.

6.3.2 CJ74HCT4051



XXXX: Code, indicates weekly record information.

7 Specifications

7.1 Absolute Maximum Ratings

Voltages are referenced to $V_{SS} = 0V$ (ground), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	Supply voltage	- (1)	-0.5	+11	V
I_{IK}	Input clamping current	$V_I < -0.5 V$ or $V_I > V_{CC} + 0.5 V$	-	± 20	mA
I_{SK}	Switch clamping current	$V_{SW} < -0.5 V$ or $V_{SW} > V_{CC} + 0.5 V$	-	± 20	mA
I_{SW}	Switch current	$-0.5 V < V_{SW} < V_{CC} + 0.5 V$	-	± 25	mA
I_{EE}	Supply current	-	-	± 20	mA
I_{CC}	Supply current	-	-	50	mA
I_{GND}	Ground current	-	-	-50	mA
T_{stg}	Storage temperature	-	-65	+150	°C
P_{tot}	Total power dissipation	-	-	500	mW
P	Power dissipation	Per switch	-	100	mW
T_L	Soldering temperature	10s	-	260	°C

- (1) To avoid drawing V_{CC} current out of terminal Z, when switch current flows into terminals Y_n , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Y_n , and in this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or V_{EE} .

7.2 Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC4051						
V_{CC}	Supply voltage	V_{CC-GND}	3.0	5.0	9.0	V
		$V_{CC-V_{EE}}$	3.0	5.0	9.0	V
V_I	Input voltage	-	0	-	V_{CC}	V
V_{SW}	Switch voltage	-	V_{EE}	-	V_{CC}	V
T_{amb}	Ambient temperature	In free air	-40	-	+125	°C
$\Delta t/\Delta V$	Input transition rise and fall rate	$V_{CC}=4.5V$	-	1.67	139	ns/V
		$V_{CC}=6.0V$	-	-	83	ns/V
		$V_{CC}=9.0V$	-	-	31	ns/V
CJ74HCT4051						
V_{CC}	Supply voltage	V_{CC-GND}	4.5	5.0	5.5	V
		$V_{CC-V_{EE}}$	3.0	5.0	9.0	V
V_I	Input voltage	-	0	-	V_{CC}	V
V_{SW}	Switch voltage	-	V_{EE}	-	V_{CC}	V
T_{amb}	Ambient temperature	In free air	-40	-	+125	°C
$\Delta t/\Delta V$	Input transition rise and fall rate	$V_{CC}=4.5V$	-	1.67	139	ns/V
		$V_{CC}=6.0V$	-	-	-	ns/V
		$V_{CC}=9.0V$	-	-	-	ns/V

7.3 ESD Ratings

SYMBOL	ESD RATINGS		VALUE	UNIT
$V_{ESD-HBM}$	Electrostatic discharge	Human body model (HBM) ⁽¹⁾	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.4 Electrical Characteristics
7.4.1 DC Characteristics 1

$T_{amb}=25^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
$R_{ON(peak)}$	ON resistance (peak)	$V_{is}=V_{CC}$ to V_{EE} ; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	100	180	Ω
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	90	160	Ω
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	70	130	Ω
$R_{ON(rail)}$	ON resistance (rail)	$V_{is}=V_{EE}$; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	80	140	Ω
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	70	120	Ω
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	60	105	Ω
		$V_{is}=V_{CC}$; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	90	160	Ω
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	80	140	Ω
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	65	120	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_{is}=V_{CC}$ to V_{EE}	$V_{CC}=4.5V$; $V_{EE}=0V$	-	9	-	Ω
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	8	-	Ω
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	6	-	Ω

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V_{IH}	HIGH-level input voltage		$V_{CC}=4.5V$	3.15	-	-	V
			$V_{CC}=6.0V$	4.2	-	-	V
			$V_{CC}=9.0V$	6.3	-	-	V
V_{IL}	LOW-level input voltage		$V_{CC}=4.5V$	-	2.1	1.35	V
			$V_{CC}=6.0V$	-	2.8	1.8	V
			$V_{CC}=9.0V$	-	4.3	2.7	V
I_i	Input leakage current	$V_{EE}=0V$; $V_i=V_{CC}$ or GND	$V_{CC}=6.0V$	-	-	±1.0	μA
			$V_{CC}=9.0V$	-	-	±1.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC}=9.0V$; $V_{EE}=0V$; $V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; See Figure 8-7	Per channel	-	-	±1.0	μA
			All channels	-	-	±1.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; $V_{CC}=9.0V$; $V_{EE}=0V$; See Figure 8-8		-	-	±1.0	μA
I_{CC}	Supply current	$V_{EE}=0V$; $V_i=V_{CC}$ or GND; $V_{is}=V_{EE}$ or V_{CC} ; $V_{os}=V_{CC}$ or V_{EE}	$V_{CC}=6.0V$	-	-	8.0	μA
			$V_{CC}=9.0V$	-	-	16.0	μA
C_i	Input capacitance		-	3.5	-	pF	

C _{SW}	Switch capacitance	Independent pins Yn		-	5	-	pF
		Common pins Z		-	25	-	pF
CJ74HCT4051							
V _{IH}	HIGH-level input voltage	V _{CC} =4.5V to 5.5V		2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} =4.5V to 5.5V		-	1.2	0.8	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =5.5V; V _{EE} =0V		-	-	±1.0	uA
I _{S(OFF)}	OFF-state leakage current	V _{CC} =9.0V; V _{EE} =0V; V _I = V _{IH} or V _{IL} ; V _{SW} =V _{CC} - V _{EE} ; See Figure 8-7	Per channel	-	-	±1.0	uA
			All channels	-	-	±1.0	uA
I _{S(ON)}	ON-state leakage current	V _{CC} = 9.0V; V _{EE} = 0V; V _I = V _{IH} or V _{IL} ; V _{SW} =V _{CC} -V _{EE} ; See Figure 8-8		-	-	±1.0	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; V _{is} =V _{EE} or V _{CC} ; V _{os} =V _{CC} or V _{EE} ;	V _{CC} =5.5V; V _{EE} =0V	-	-	8.0	uA
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	16.0	uA
ΔI _{CC}	Additional supply current	Per input; V _I =V _{CC} -2.1V; Other inputs at V _{CC} or GND; V _{CC} =4.5V to 5.5V; V _{EE} =0V		-	50	180	uA
C _I	Input capacitance	-		-	3.5	-	pF
C _{SW}	Switch capacitance	Independent pins Yn		-	5	-	pF
		Common pins Z		-	25	-	pF

Note:

- (1) V_I= V_{IH} or V_{IL}; for test circuit see Figure 8-5.
- (2) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (3) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.2 DC Characteristics 2

T_{amb} = -40°C ~85°C, voltages are reference to GND (ground=0V), unless otherwise specified, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
R _{ON(peak)}	ON resistance (peak)	V _{is} =V _{CC} to V _{EE} ; I _{SW} =1000uA	V _{CC} =4.5V; V _{EE} =0V	-	-	225	Ω
			V _{CC} =6.0V; V _{EE} =0V	-	-	200	Ω
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	165	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} =V _{EE} ; I _{SW} =1000uA	V _{CC} =4.5V; V _{EE} =0V	-	-	175	Ω
			V _{CC} =6.0V; V _{EE} =0V	-	-	150	Ω
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	130	Ω
		V _{is} =V _{CC} ; I _{SW} =1000uA	V _{CC} =4.5V; V _{EE} =0V	-	-	200	Ω
			V _{CC} =6.0V; V _{EE} =0V	-	-	175	Ω
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	150	Ω

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V _{IH}	HIGH-level input voltage	V _{CC} =4.5V	3.15	-	-	V
		V _{CC} =6.5V	4.2	-	-	V
		V _{CC} =9.5V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} =4.5V	-	-	1.35	V

		$V_{CC}=6.5V$		-	-	1.8	V
		$V_{CC}=9.5V$		-	-	2.7	V
I_i	Input leakage current	$V_{EE}=5V$; $V_i=V_{CC}$ or GND	$V_{CC}=6.5V$	-	-	± 1.0	μA
			$V_{CC}=9.5V$	-	-	± 2.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC}=9.0V$; $V_{EE}=0V$; $V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; See Figure 8-7	Per channel	-	-	± 1.0	μA
			All channels	-	-	± 4.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; $V_C=9.0V$; $V_{EE}=0V$; See Figure 8-8		-	-	± 4.0	μA
I_{CC}	Supply current	$V_{EE}=0V$; $V_i=V_{CC}$ or GND; $V_{is}=V_{EE}$ or V_{CC} ; $V_{os}=V_{CC}$ or V_{EE}	$V_{CC}=6.0V$	-	-	80.0	μA
			$V_{CC}=9.0V$	-	-	160.0	μA

CJ74HCT4051

V_{IH}	HIGH-level input voltage	$V_{CC}=4.5V$ to $5.5V$		2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC}=4.5V$ to $5.5V$		-	-	0.8	V
I_i	Input leakage current	$V_i=V_{CC}$ or GND; $V_{CC}=5.5V$; $V_{EE}=0V$		-	-	± 1.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC}=9.0V$; $V_{EE}=0V$; $V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; See Figure 8-7	Per channel	-	-	± 1.0	μA
			All channels	-	-	± 4.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC}=9.0V$; $V_{EE}=0V$; $V_i=V_{IH}$ or V_{IL} ; $ V_{SW} =V_{CC}-V_{EE}$; See Figure 8-8		-	-	± 4.0	μA
I_{CC}	Supply current	$V_i=V_{CC}$ or GND; $V_{is}=V_{EE}$ or V_{CC} ; $V_{os}=V_{CC}$ or V_{EE}	$V_{CC}=5.5V$; $V_{EE}=0V$	-	-	80.0	μA
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	-	160	μA
ΔI_{CC}	Additional supply current	Per input; $V_i=V_{CC}-2.1V$; Other inputs at V_{CC} or GND; $V_{CC}=4.5V$ to $5.5V$; $V_{EE}=0V$		-	-	225	μA

Note:

- (1) $V_i=V_{IH}$ or V_{IL} ; for test circuit See Figure 8-5.
- (2) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (3) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.3 DC Characteristics 3

$T_{amb} = -40^{\circ}C \sim 125^{\circ}C$ voltages are reference to GND (ground=0V), unless otherwise specified, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT	
$R_{ON(peak)}$	ON resistance (peak)	$V_{is}=V_{CC}$ to V_{EE} ; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	-	270	Ω	
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	-	240	Ω	
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	-	195	Ω	
$R_{ON(rail)}$	ON resistance (rail)	$V_{is}=V_{EE}$; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	-	210	Ω	
			$V_{CC}=6.0V$; $V_{EE}=0V$	-	-	180	Ω	
			$V_{CC}=4.5V$; $V_{EE}=-4.5V$	-	-	160	Ω	
			$V_{is}=V_{CC}$; $I_{SW}=1000\mu A$	$V_{CC}=4.5V$; $V_{EE}=0V$	-	-	240	Ω
				$V_{CC}=6.0V$; $V_{EE}=0V$	-	-	210	Ω

			$V_{CC}=4.5V; V_{EE}=-4.5V$	-	-	180	Ω
CJ74HC4051							
V_{IH}	HIGH-level input voltage	$V_{CC}=4.5V$		3.15	-	-	V
		$V_{CC}=6.0V$		4.2	-	-	V
		$V_{CC}=9.0V$		6.3	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC}=4.5V$		-	-	1.35	V
		$V_{CC}=6.0V$		-	-	1.8	V
		$V_{CC}=9.0V$		-	-	2.7	V
I_i	Input leakage current	$V_{EE}=0V;$ $V_i=V_{CC}$ or GND	$V_{CC}=6.0V$	-	-	± 1.0	μA
			$V_{CC}=9.0V$	-	-	± 2.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC}=9.0V;$ $V_{EE}=0V;$ $V_i=V_{IH}$ or $V_{IL};$ $ V_{SW} =V_{CC}-V_{EE};$ See Figure 8-7	Per channel	-	-	± 1.0	μA
			All channels	-	-	± 4.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_i=V_{IH}$ or $V_{IL}; V_{SW} =V_{CC}-V_{EE}; V_{CC}=9.0V;$ $V_{EE}=0V;$ See Figure 8-8		-	-	± 4.0	μA
I_{CC}	Supply current	$V_{EE}=0V;$ $V_i=V_{CC}$ or GND; $V_{is}=V_{EE}$ or $V_{CC};$ $V_{os}=V_{CC}$ or V_{EE}	$V_{CC}=6.0V$	-	-	160.0	μA
			$V_{CC}=9.0V$	-	-	320.0	μA
CJ74HCT4051							
V_{IH}	HIGH-level input voltage	$V_{CC}=4.0V$ to $5.0V$		2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC}=4.0V$ to $5.0V$		-	-	0.8	V
I_i	Input leakage current	$V_i=V_{CC}$ or GND; $V_{CC}=5.0V; V_{EE}=0V$		-	-	± 1.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC}=9.0V;$ $V_{EE}=0V;$ $V_i=V_{IH}$ or $V_{IL};$ $ V_{SW} =V_{CC}-V_{EE};$ See Figure 8-7	Per channel	-	-	± 1.0	μA
			All channels	-	-	± 4.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC}=9.0V; V_{EE}=0V; V_i=V_{IH}$ or $V_{IL};$ $ V_{SW} =V_{CC}-V_{EE};$ See Figure 8-8		-	-	± 4.0	μA
I_{CC}	Supply current	$V_i=V_{CC}$ or GND; $V_{is}=V_{EE}$ or $V_{CC};$ $V_{os}=V_{CC}$ or V_{EE}	$V_{CC}=5.5V; V_{EE}=0V$	-	-	160.0	μA
			$V_{CC}=4.5V; V_{EE}=-4.5V$	-	-	320.0	μA
ΔI_{CC}	Additional supply current	Per input; $V_i=V_{CC}-2.1V;$ Other inputs at V_{CC} or GND; $V_{CC}=4.0V$ to $5.0V; V_{EE}=0V$		-	-	245	μA

Note:

- (1) $V_i=V_{IH}$ or $V_{IL};$ for test circuit See Figure 8-5.
- (2) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (3) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.4 AC Characteristics 1

T_{amb}=25°C, GND = 0 V; t_r= t_f = 6 ns; C_L= 50 pF; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
CJ74HC4051							
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	5	12	ns
			V _{CC} =6.0V; V _{EE} =0V	-	4	10	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	4	8	ns
t _{on}	Turn-on time	Ē to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	29	69	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	22	-	ns
			V _{CC} =6.0V; V _{EE} =0V	-	21	59	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	18	51	ns
		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	28	69	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	20	-	ns
			V _{CC} =6.0V; V _{EE} =0V	-	19	59	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	16	51	ns
t _{off}	Turn-off time	Ē to V _{os} ; R _L = 1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	31	58	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	18	-	ns
			V _{CC} =6.0V; V _{EE} =0V	-	17	49	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	18	42	ns
		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	25	58	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	19	-	ns
			V _{CC} =6.0V; V _{EE} =0V	-	18	49	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	18	42	ns
C _{PD}	Power dissipation capacitance	Per switch; V _I = GND to V _{CC} ⁽⁴⁾	-	25	-	pF	
CJ74HCT4051							
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	5	12	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	4	8	ns
t _{on}	Turn-on time	Ē to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	26	55	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	22	-	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	16	39	ns
		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	28	55	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	24	-	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	16	39	ns
t _{off}	Turn-off time	Ē to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	19	45	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	16	-	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	16	32	ns

		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	23	45	ns
			V _{CC} =5.0V; V _{EE} =0V; C _L =15pF	-	20	-	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	16	32	ns
C _{PD}	Power dissipation capacitance	Per switch; V _I = GND to V _{CC} -1.5V ⁽⁴⁾		-	25	-	pF

- (1) t_{pd} is the same as t_{PHL} and t_{PLH}.
- (2) t_{on} is the same as t_{PZH} and t_{PZL}.
- (3) t_{off} is the same as t_{PHZ} and t_{PLZ}.
- (4) C_{PD} is used to determine the dynamic power dissipation (P_D in uW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma\{(C_L + C_{SW}) \times V_{CC}^2 \times f_o\}$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 N = number of inputs switching;
 Σ{(C_L + C_{SW}) x V_{CC}² x f_o} = sum of outputs;
 C_L = output load capacitance in pF;
 C_{SW} = switch capacitance in pF;
 V_{CC} = supply voltage in V.
- (5) For test circuit see Figure 8-11.
- (6) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (7) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.5 AC Characteristics 2

T_{amb}= -40°C ~+85°C; GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC4051						
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	15 ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	13 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	10 ns
t _{on}	Turn-on time	Ē to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	86 ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	73 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	64 ns
		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	86 ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	73 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	64 ns
t _{off}	Turn-off time	Ē to V _{os} ; R _L = 1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	73 ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	62 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	53 ns
		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	73 ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	62 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	53 ns
CJ74HCT4051						
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	15 ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	10 ns

t _{on}	Turn-on time	\bar{E} to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	69	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	49	ns
		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	69	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	49	ns
t _{off}	Turn-off time	\bar{E} to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	56	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	40	ns
		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	56	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	40	ns

- (1) t_{pd} is the same as t_{PHL} and t_{PLH}.
- (2) t_{on} is the same as t_{PZH} and t_{PZL}.
- (3) t_{off} is the same as t_{PHZ} and t_{PLZ}.
- (4) For test circuit see Figure 8-11.
- (5) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (6) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.6 AC Characteristics 3

T_{amb}= -40°C ~+125°C; GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
CJ74HC4051							
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	18	ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	15	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	12	ns
t _{on}	Turn-on time	\bar{E} to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	104	ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	88	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	77	ns
		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	104	ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	88	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	77	ns
t _{off}	Turn-off time	\bar{E} to V _{os} ; R _L = 1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	87	ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	74	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	72	ns
		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	87	ns
			V _{CC} =6.0V; V _{EE} =0V	-	-	74	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	72	ns
CJ74HCT4051							
t _{pd}	Propagation delay	V _{is} to V _{os} ; R _L =∞ Ω; See Figure 8-9 ⁽¹⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	18	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	12	ns
t _{on}	Turn-on time	\bar{E} to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	83	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	59	ns

		Sn to V _{os} ; R _L =∞ Ω; See Figure 8-10 ⁽²⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	83	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	59	ns
t _{off}	Turn-off time	Ē to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	68	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	48	ns
		Sn to V _{os} ; R _L =1 kΩ; See Figure 8-10 ⁽³⁾	V _{CC} =4.5V; V _{EE} =0V	-	-	68	ns
			V _{CC} =4.5V; V _{EE} =-4.5V	-	-	48	ns

- (1) t_{pd} is the same as t_{PHL} and t_{PLH}.
- (2) t_{on} is the same as t_{PZH} and t_{PZL}.
- (3) t_{off} is the same as t_{PHZ} and t_{PLZ}.
- (4) For test circuit see Figure 8-11.
- (5) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (6) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

7.4.7 AC Characteristics 4

T_{amb}=25°C; GND = 0 V; C_L = 50 pF; recommended conditions and typical values.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
d _{sin}	Sine-wave distortion	f _i =1 kHz; R _L =10 kΩ; See Figure 8-12	V _{is} =4.0V (p-p); V _{CC} =2.25V; V _{EE} =-2.25V	-	0.04	-	%
			V _{is} =8.0V (p-p); V _{CC} =4.5V; V _{EE} =-4.5V	-	0.02	-	%
		f _i =10 kHz; R _L =10 kΩ; See Figure 8-12	V _{is} =4.0V (p-p); V _{CC} =2.25V; V _{EE} =-2.25V	-	0.12	-	%
			V _{is} =8.0V (p-p); V _{CC} =4.5V; V _{EE} =-4.5V	-	0.06	-	%
α _{iso}	Isolation (OFF-state)	R _L =600 Ω; f _i =1 MHz; See Figure 8-13	V _{CC} =2.25V; ⁽¹⁾ V _{EE} =-2.25V	-	-50	-	dB
			V _{CC} =4.5V; ⁽¹⁾ V _{EE} =-4.5V	-	-50	-	dB
V _{ct}	Crosstalk voltage	Peak-to-peak value; between control and any switch; R _L =600 Ω; f _i =1MHz; Ē or Sn square wave Between V _{CC} and GND; t _r =t _f =6 ns; See Figure 8-14	V _{CC} =4.5V; V _{EE} =0V	-	110	-	mV
			V _{CC} =4.5V; V _{EE} =-4.5V	-	220	-	mV
f _(-3dB)	-3dB frequency response	R _L =50 Ω; See Figure 8-15	V _{CC} =2.25V; ⁽²⁾ V _{EE} =-2.25V	-	170	-	MHz
			V _{CC} =4.5V; ⁽²⁾ V _{EE} =-4.5V	-	180	-	MHz

- (1) Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
- (2) Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).
- (3) V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.
- (4) V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

8 Detailed Description

8.1 Overview

The CJ74HC/HCT4051 is a single-pole octal-throw analog switch (SP8T) suitable for use in analog or digital 8:1 multiplexer/demultiplexer applications. The switch features three digital select inputs (S0, S1 and S2), eight independent inputs/outputs (Yn), a common input/output (Z) and a digital enable input (/E). When /E is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of Vcc.

8.2 Functional Block Diagram

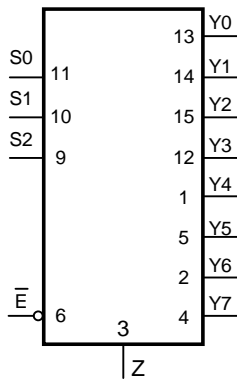


Figure 8-1 Logic symbol

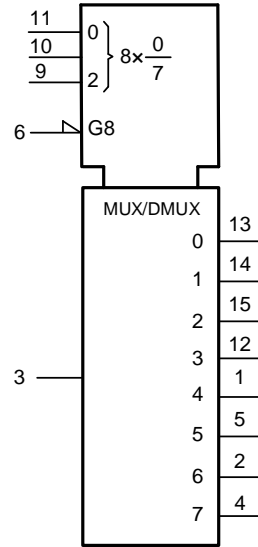


Figure 8-2 IEC logic symbol

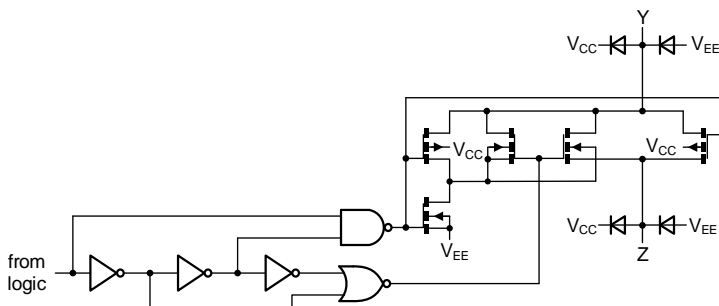


Figure 8-3 Schematic diagram (one switch)

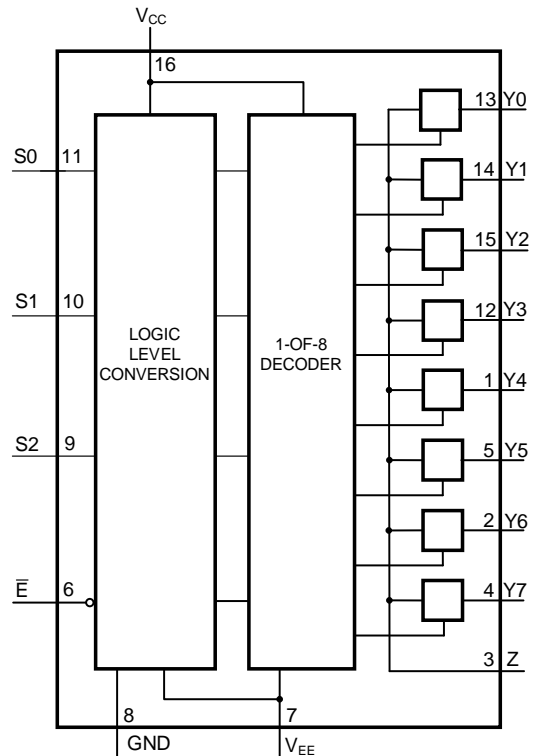


Figure 8-4 Functional diagram

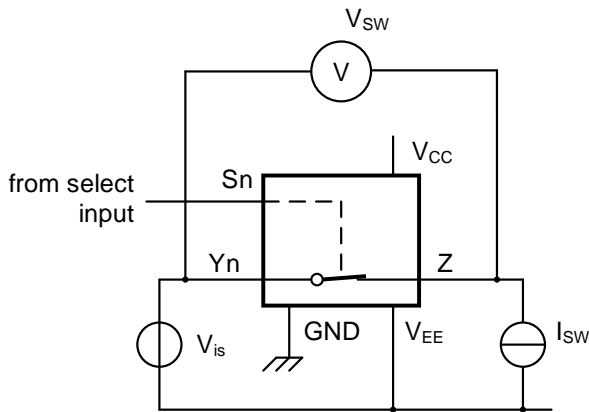
8.3 Function Table⁽¹⁾

INPUT				CHANNEL ON
\bar{E}	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	H	Y1 to Z
L	L	H	L	Y2 to Z
L	L	H	H	Y3 to Z
L	H	L	L	Y4 to Z
L	H	L	H	Y5 to Z
L	H	H	L	Y6 to Z
L	H	H	H	Y7 to Z
H	X	X	X	Switches off

(1) H=HIGH voltage level; L=LOW voltage level; X=don't care.

8.4 Testing Circuit

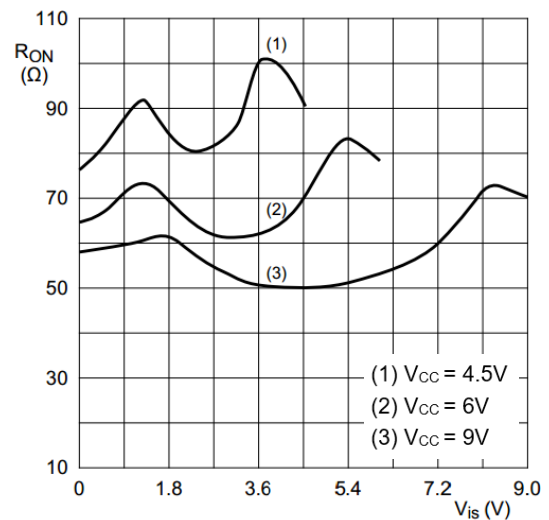
8.4.1 DC Testing Circuit 1



$$V_{is} = 0V \text{ to } (V_{CC} - V_{EE})$$

$$R_{ON} = V_{SW} / I_{SW}$$

Figure 8-5 Test circuit for measuring R_{ON}



$$V_{is} = 0V \text{ to } (V_{CC} - V_{EE})$$

Figure 8-6 Typical R_{ON} as a function of input voltage V_{is}

8.4.2 DC Testing Circuit 2

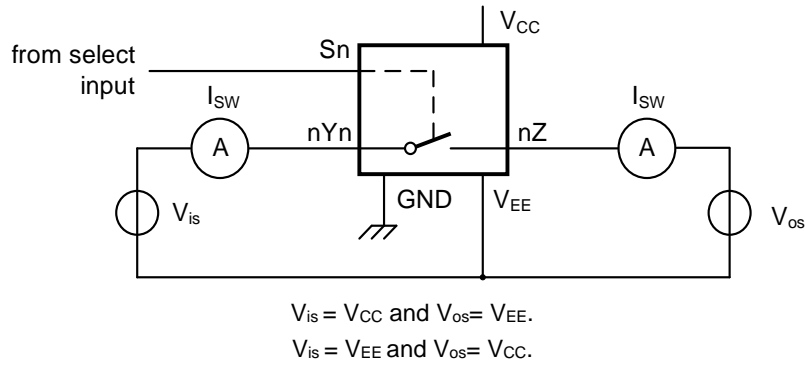


Figure 8-7 Test circuit for measuring OFF-state current

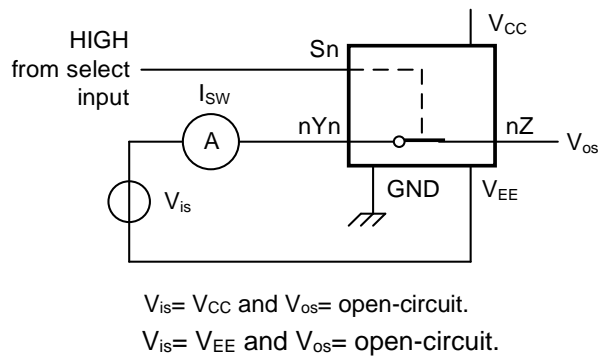


Figure 8-8 Test circuit for measuring ON-state current

8.4.3 AC Testing Waveforms

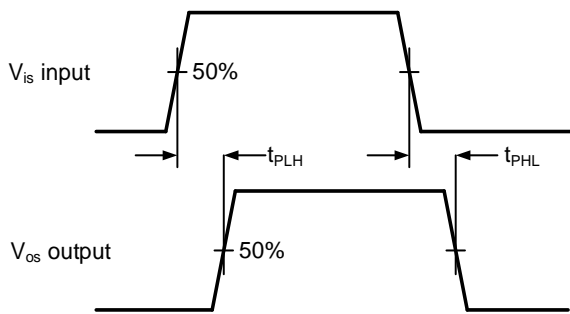
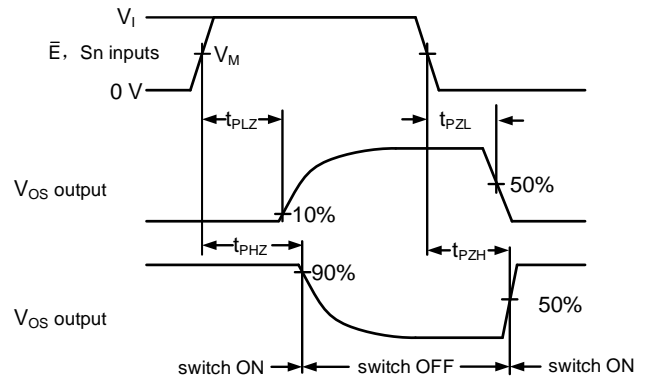


Figure 8-9 Input (V_{is}) to output (V_{os}) propagation delays



For CJ74HC4051: $V_M = 0.5 \times V_{CC}$.
 For CJ74HCT4051: $V_M = 1.3 \text{ V}$.

Figure 8-10 Turn-on and turn-off times

8.4.4 AC Testing Circuit 1

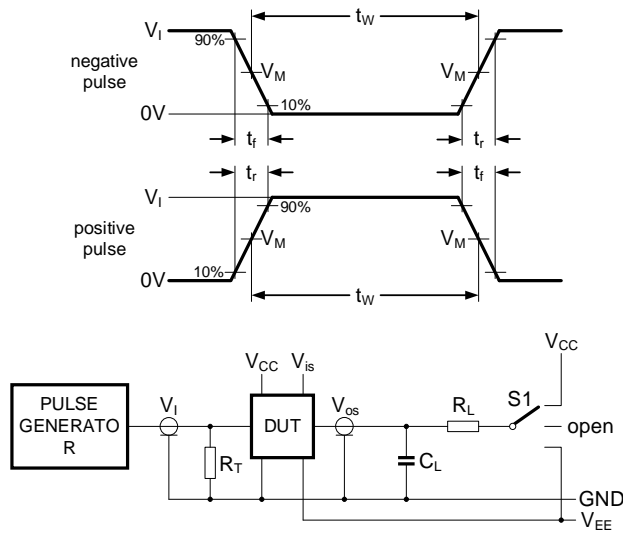


Figure 8-11 Test circuit for measuring switching times

Definitions for test circuit:

R_T = termination resistance should be equal to the output impedance Z_O of the pulse generator.

C_L = load capacitance including jig and probe capacitance.

R_L = load resistance.

$S1$ = Test selection switch.

8.4.5 AC Testing Circuit 2

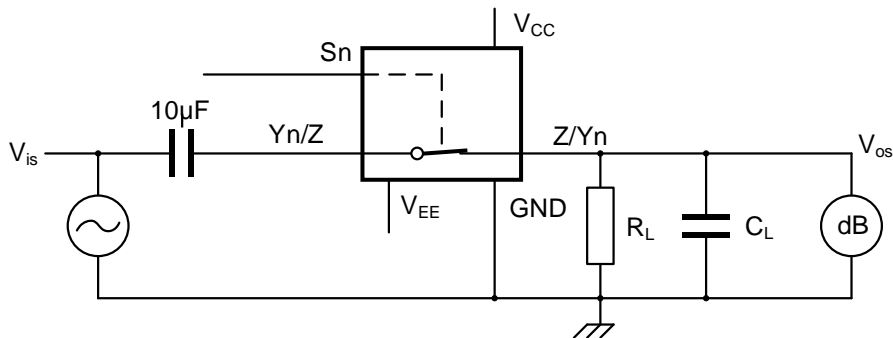
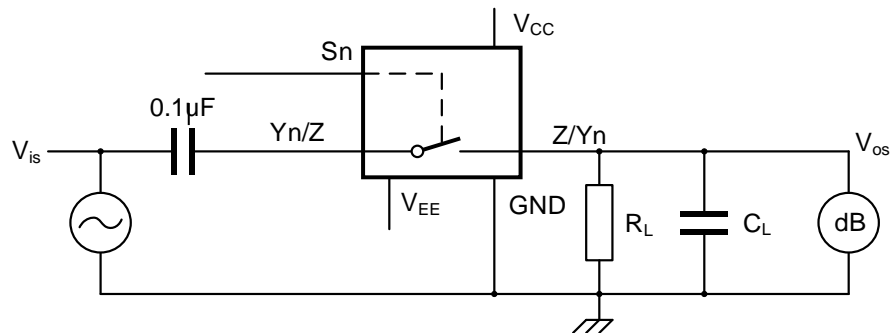
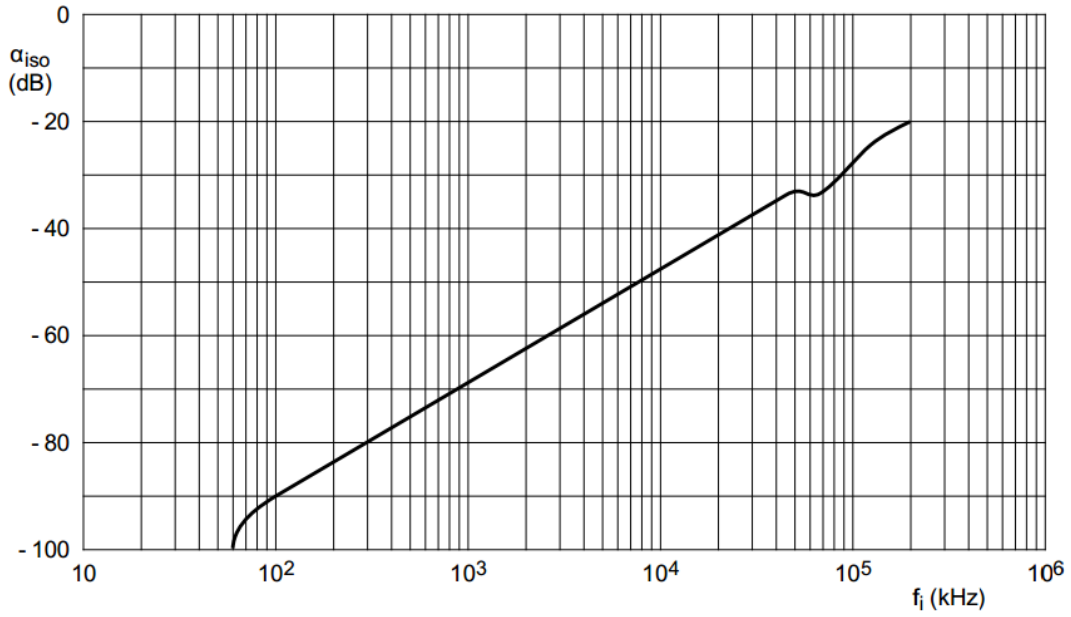


Figure 8-12 Test circuit for measuring sine-wave distortion



$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $V_{EE} = -4.5\text{ V}$; $R_L = 600\ \Omega$; $R_S = 1\text{ k}\Omega$.

a. Test circuit



b. Isolation (OFF-state) as a function of frequency

Figure 8-13 Test circuit for measuring isolation (OFF-state)

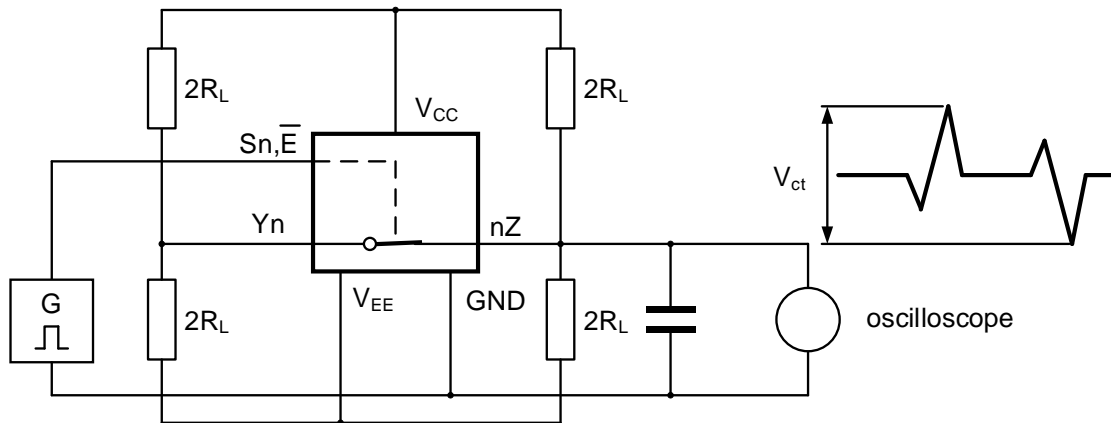
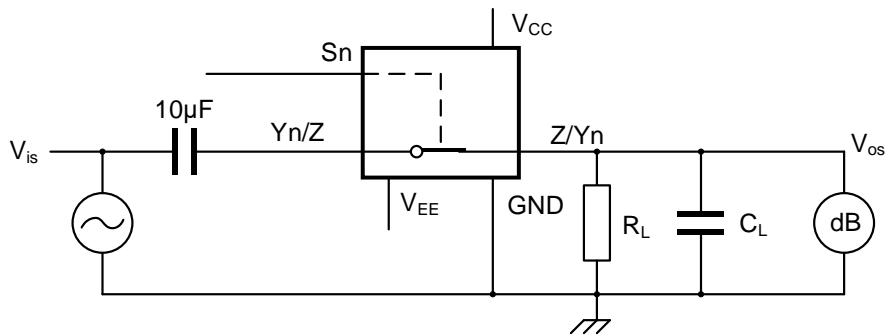
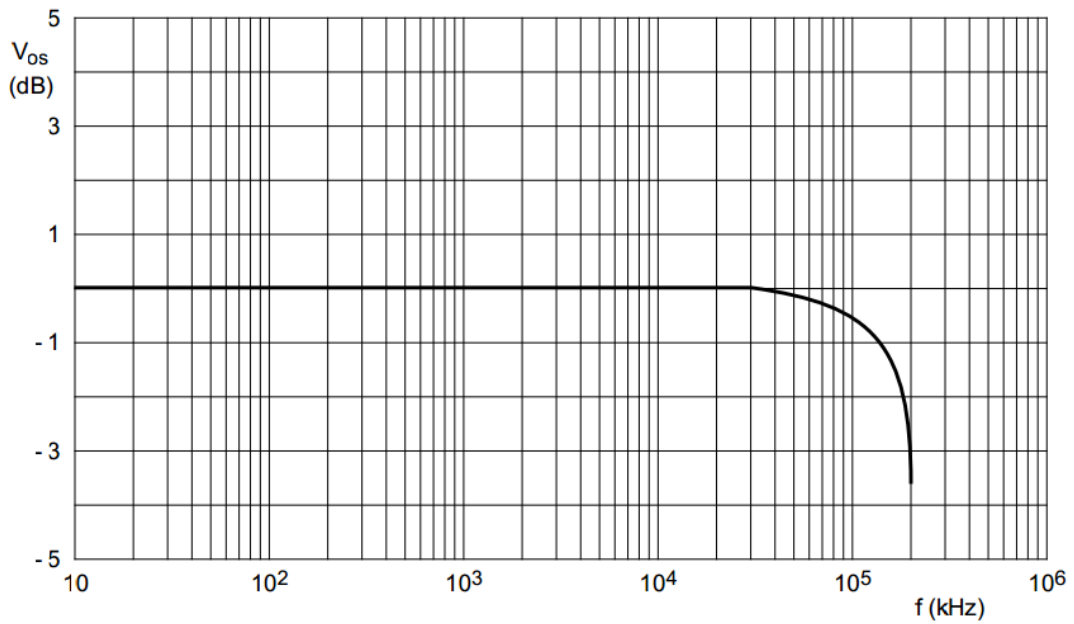


Figure 8-14 Test circuit for measuring crosstalk between control input and any switch



$V_{CC} = 4.5\text{ V}; GND = 0\text{ V}; V_{EE} = -4.5\text{ V}; R_L = 50\ \Omega; R_S = 1\text{ k}\Omega$

a. Test circuit



b. Typical frequency response

Figure 8-15 Test circuit for frequency response

8.4.6 Test Data

TEST	INPUT				LOAD		S1 POSITION
	V _I	V _{is}	t _r , t _f		C _L	R _L	
			at f _{max}	Other ⁽¹⁾			
t _{PHL} , t _{PLH}	(2)	Pulse	< 2ns	6ns	50pF	1kΩ	Open
t _{PZH} , t _{PHZ}	(2)	V _{CC}	< 2ns	6ns	50pF	1kΩ	V _{EE}
t _{PZL} , t _{PLZ}	(2)	V _{EE}	< 2ns	6ns	50pF	1kΩ	V _{CC}

(1) t_r = t_f = 6 ns; when measuring f_{max}, there is no constraint to t_r and t_f with 50 % duty factor.

(2) V_I values:

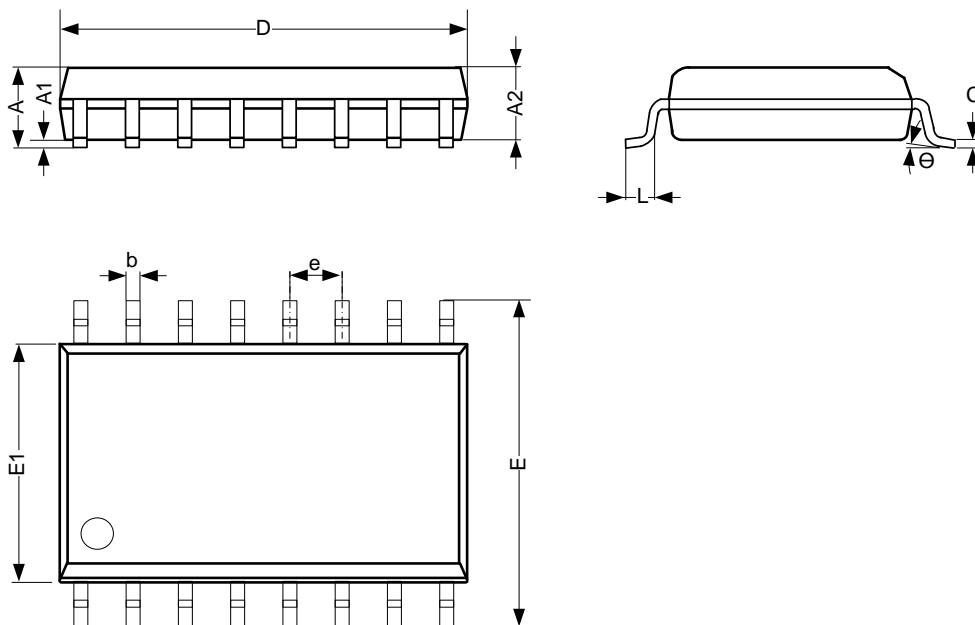
For CJ74HC4051: V_I = V_{CC}.

For CJ74HCT4051: V_I = 3V.

9 Mechanical Information

9.1 SOP16 Mechanical Information

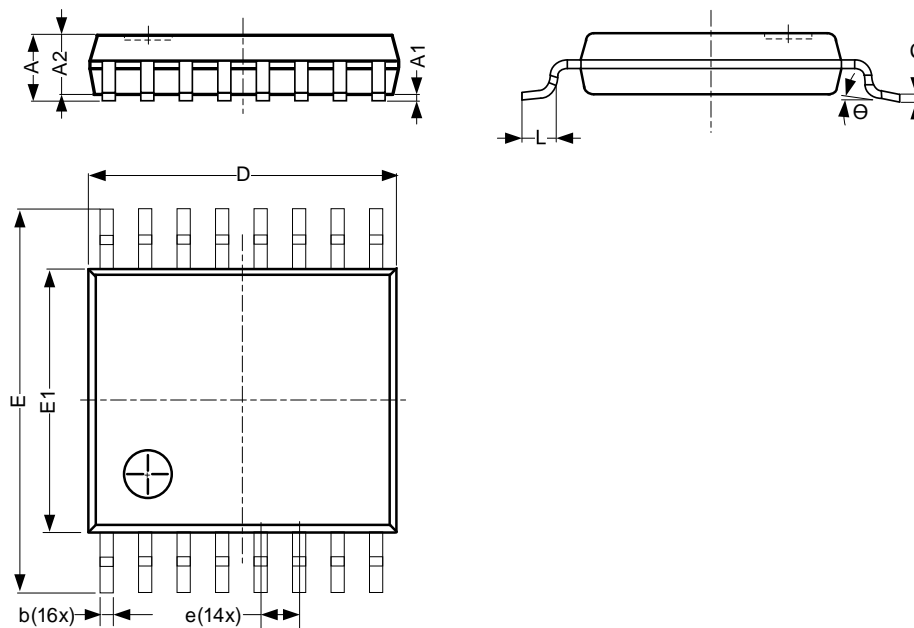
9.1.1 SOP16 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	1.35	-	1.80
A1	0.10	-	0.25
A2	1.25	-	1.55
b	0.33	-	0.51
c	0.19	-	0.25
D	9.50	-	10.10
E	5.80	-	6.30
E1	3.70	-	4.10
e	1.27 BSC		
L	0.35	-	0.89
θ	0°	-	8°
Unit: mm			

9.2 TSSOP16 Mechanical Information

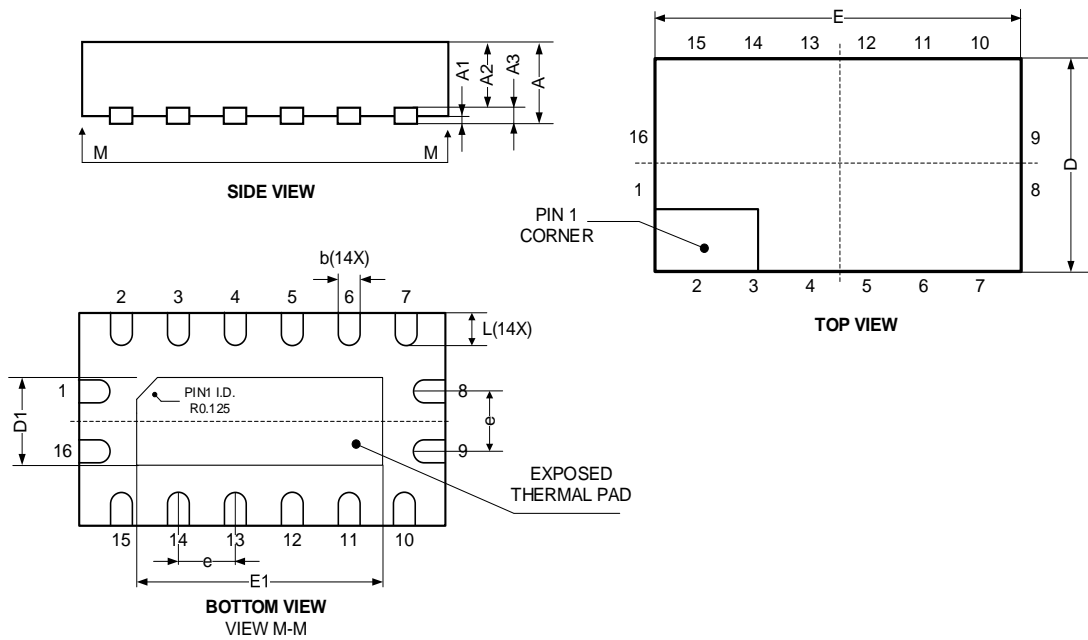
9.2.1 TSSOP16 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	-	-	1.20
A1	0.05	-	0.15
A2	0.80	-	1.05
b	0.19	-	0.30
c	0.09	-	0.20
D	4.90	-	5.10
E	6.20	-	6.60
E1	4.30	-	4.50
e	0.65 BSC		
L	0.45	-	0.75
Θ	0°	-	8°
Unit: mm			

9.3 QFN3.5x2.5-16L Mechanical Information

9.3.1 QFN3.5x2.5-16L Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.80	-	1.00
A1	0.00	-	0.05
A2	0.60	-	0.70
A3	-	0.20	-
D	2.40	-	2.60
E	3.40	-	3.60
e	0.50 BSC		
b	0.18	-	0.30
L	0.30	-	0.50
D1	0.85	-	1.15
E1	1.85	-	2.15
Unit: mm			

10 Notes and Revision History

10.1 Associated Product Family and Others

To view other products of the same type or IC products of other types, click the official website of JSCJ -- <https://www.jscj-elec.com> for more details.

10.2 Notes

Electrostatic Discharge Caution



This IC may be damaged by ESD. Relevant personnel shall comply with correct installation and use specifications to avoid ESD damage to the IC. If appropriate measures are not taken to prevent ESD damage, the hazards caused by ESD include but are not limited to degradation of integrated circuit performance or complete damage of integrated circuit. For some precision integrated circuits, a very small parameter change may cause the whole device to be inconsistent with its published specifications.

DISCLAIMER

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